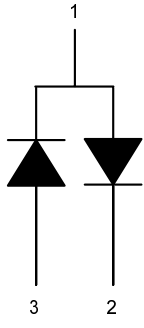
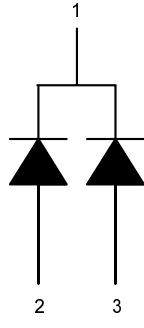
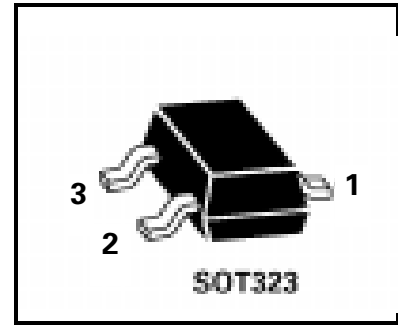


SOT323 SILICON PLANAR DUAL SCHOTTKY BARRIER DIODES

ZUMD70-04
ZUMD70-05

ISSUE 1 - NOVEMBER 1998

	
SERIES PAIR	COMMON CATHODE
Device Type: ZUMD70-04	Device Type: ZUMD70-05
Partmarking Detail: D94	Partmarking Detail: D95



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^{\circ}C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Breakdown Voltage	V_{BR}	70		V	$I_R=10\mu A$
Reverse Leakage Current	I_R		200	nA	$V_R=50V$
Forward Voltage	V_F		410	mV	$I_F=1mA$
Forward Current	I_F	15		mA	$V_F=1V$
Capacitance	C_T		2.0	pF	$f=1MHz, V_R=0$
Effective Minority Lifetime (1)	τ		100	ps	$f=54MHz, I_{pk}=20mA$ (Krakauer Test Method)

(1) Sample Test

For typical characteristics graphs see ZC2800E datasheet.